



60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C (Note 8)
60)/	$3.1 \text{m}\Omega$ @ $V_{GS} = 10V$	100A
60V	4.5mΩ @ V _{GS} = 4.5V	100A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- · Primary Switch in Isolated DC-DC
- Synchronous Rectifier
- Load Switch

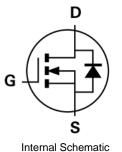
Features

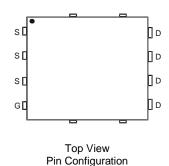
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Q_a Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMTH6004LPSQ</u>)

Mechanical Data

- Case: POWERDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 (§3)
- · Weight: 0.097 grams (Approximate)







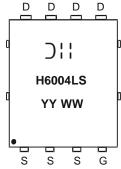
Ordering Information (Note 4)

·		
Part Number	Case	Packaging
DMTH6004LPS-13	POWERDI®5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



);; = Manufacturer's Marking
H6004LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 14 = 2014)
WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V_{DSS}	60	V
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current (Note 5) $ T_A = +25^{\circ}C $ $ T_A = +70^{\circ}C $		I _D	22 16	А
Continuous Drain Current (Note 6)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$ (Note 8)	l _D	100 100	А
Maximum Continuous Body Diode Forward Current (Note 6)	I _S	100	Α	
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)		I _{DM}	120	Α
Avalanche Current, L = 0.2mH		I _{AS}	40	Α
Avalanche Energy, L = 0.2mH		E _{AS}	160	mJ

Thermal Characteristic

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	47	°C/W	
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		P_D	138	W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	0.9	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

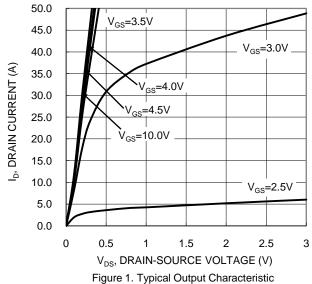
Characteristic	Symbol	Min	Tyrn	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Symbol	IVIII	Тур	IVIAX	Unit	rest Condition	
Drain-Source Breakdown Voltage	D\/	60	_	l <u>-</u>	V	\\\ 0\\ I 1 1 m A	
	BV _{DSS}	60	-	1	-	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-		μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	1	1	1	1	1	T	
Gate Threshold Voltage	V _{GS(TH)}	1	-	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D	-	2.5	3.1	mΩ	$V_{GS} = 10V, I_D = 25A$	
Static Dialii-Source Off-Resistance	R _{DS(ON)}	-	3.3	4.5	mΩ	$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	V_{SD}	-	-	1.3	V	$V_{GS} = 0V, I_{S} = 25A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	-	4515	-			
Output Capacitance	Coss	-	1477	14// - 0F		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	-	135.3	-		I = IIVIDZ	
Gate Resistance	Rg	-	0.64	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Q_{g}	-	96.3	-			
Total Gate Charge (V _{GS} = 4.5V)	Q_g	-	47.4	-	nC	$V_{DD} = 30V, I_D = 25A$	
Gate-Source Charge	Q_{gs}	-	14.1	-	IIC		
Gate-Drain Charge	Q_{gd}	-	21.4	-			
Turn-On Delay Time	t _{D(ON)}	-	9.9	-			
Turn-On Rise Time	t _R	-	17.7	-		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 25A, R_G = 3.5\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	-	53.5	-	ns		
Turn-Off Fall Time	t _F	-	32.9	-			
Body Diode Reverse Recovery Time	t _{RR}	-	49.7	-	ns	1 25A di/dt 100A/us	
Body Diode Reverse Recovery Charge	Q _{RR}	-	78.9	-	nC	I _F = 25A, di/dt = 100A/μs	

Notes:

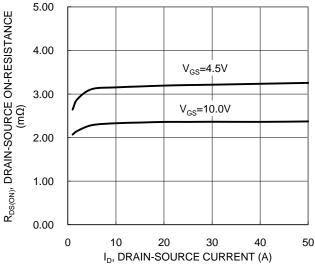
- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 6. Thermal resistance from junction to soldering point (on the exposed drain pad).
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to production testing.



DMTH6004LPS







 $\rm I_D,\,DRAIN\text{-}SOURCE$ CURRENT (A) Figure 3. Typical On-Resistance $\,$ vs. Drain Current and Gate Voltage

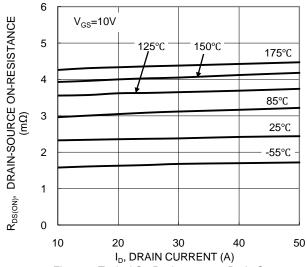
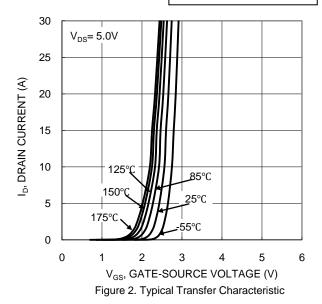
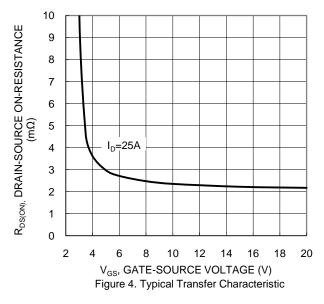


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





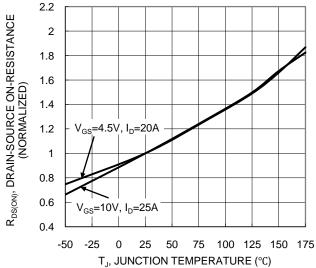


Figure 6. On-Resistance Variation with Temperature





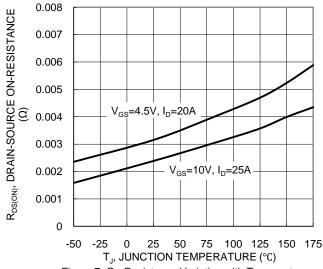


Figure 7. On-Resistance Variation with Temperature

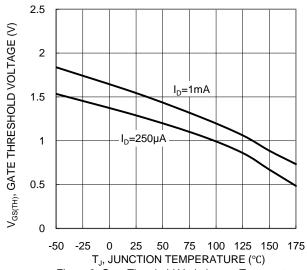
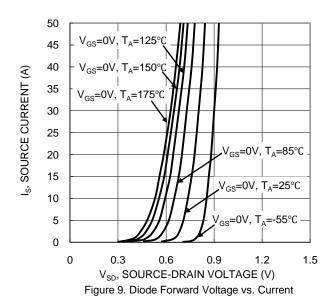
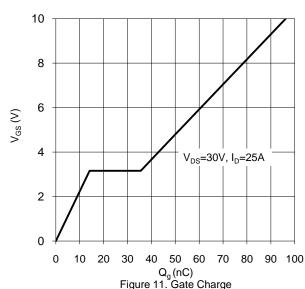
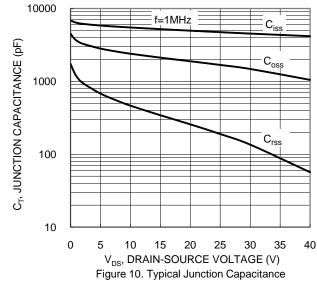
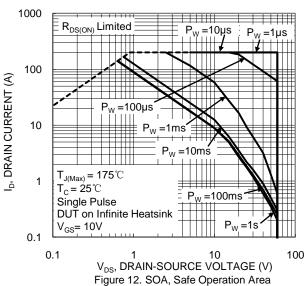


Figure 8. Gate Threshold Variation vs. Temperature











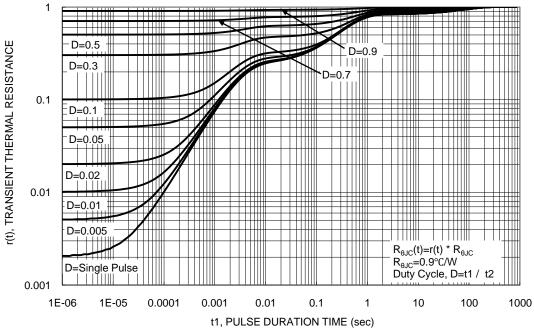
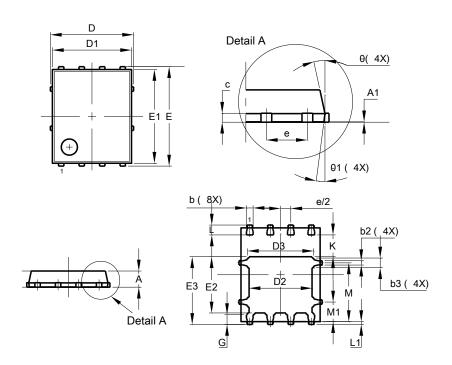


Figure 13. Transient Thermal Resistance



Package Outline Dimensions

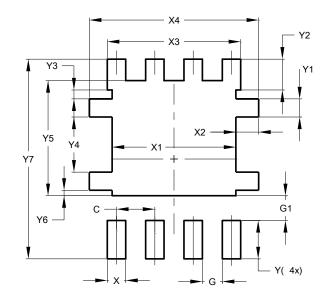
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



POWERDI [®] 5060-8						
Dim	Min Max		Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
E		6.15 BSC				
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
θ	10°	12º	11º			
θ1	6°	8º	7º			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com